

Product Features

Operating Frequency: 10MHz ~ 4GHz
 Attenuation Range: 0.5dB LSB Steps to 31.5dB
 Parallel Control Interface
 TTL/CMOS-Compatible Control
 Maximum Attenuation Error:
 $\pm (0.4+2\% \times \text{attenuation amount}) \text{ dB}$
 +5V/+3.3V Power Supply
 Package: QFN24

Application

4G Infrastructure and Hotspot Devices
 Microcellular /3G/4G and UWB
 WiMAX, WiBN & Fixed Wireless
 Test Equipment and Sensors
 Short-wave and Ultra-short-wave Wireless
 Communication Equipment

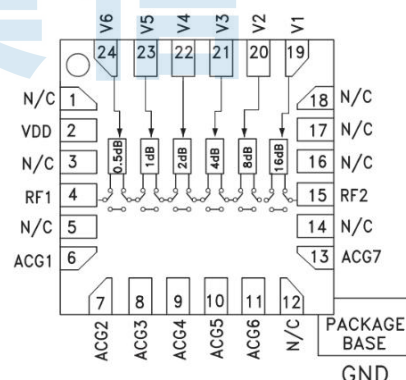
General Description

The BR9155FP is a wideband 6-bit digital attenuator in a low-cost leadless surface-mount QFN24 package. This single positive control line per bit digital attenuator incorporates off chip AC ground capacitors for near DC operation, making it suitable for a wide variety of RF and IF applications. Covering a frequency band of 10MHz to 4GHz, the BR9155FP typically offers insertion loss of less than 3dB, and can be programmed to provide an attenuation range of 31.75dB in 0.25dB steps with maximum attenuation error of $\pm(0.8+2\%) \text{ dB}$. 6-bit TTL/CMOS control inputs are used to select each attenuation state. A single Vdd bias of +5V/+3.3V is required.

Ordering Information

Part Number	Package	Description
BR9155FP	QFN24	10MHz ~ 4GHz 6-bit Parallel Digital Attenuator

Functional Block Diagram



Electrical Specifications

Parameter	Test Conditions	Min.	Typ.	Max.	Units
Insertion Loss	0.01GHz to 1.0GHz	-1.0	-1.3	-1.7	dB
	1.0GHz to 4.0GHz	-1.7	-2.5	-3.1	
Attenuation Range	0.01GHz to 4.0GHz	0.5	-	31.5	dB
Input Return Loss	0.01GHz to 4.0GHz	-	-15	-	dB
Output Return Loss	0.01GHz to 4.0GHz	-	-15	-	dB
Attenuation Accuracy: (reference insertion loss) 0.5dB ~ 16dB attenuation state 16.5dB ~ 31.5dB attenuation state	0.01GHz to 4.0GHz	$\pm (0.2+2\% \text{ attenuation amount})$ $\pm (0.4+2\% \text{ attenuation amount})$			dB
Input Power for 1dB Compression	0.6GHz to 2.5GHz	32	33	34	dBm
Input-Third-Order Interception	0.05GHz ~ 4GHz	38	-	-	dBm
Switching Characteristics Trise (50% CTL-90% RF) Tfall (50% CTL-10% RF)	200MHz at 16dB attenuation state	- -	70 70	- -	ns ns

Test Conditions: VDD=+5V, I=3mA, Input IP3 spacing=1MHz, Pin=0dBm/tone, Temp.=+25°C

Absolute Maximum Ratings

Maximum Operating Voltage: +5.5V;

Maximum RF Input Power:

27dBm (All Attenuated states);

Control Voltage Range: 0V ~ VDD;

Recommended Operating Conditions

Supply Voltage: 5V/3.3V;

Control Voltage Threshold:

0V ~ 0.8V (low level);

2.7V ~ VDD (high level);

Storage Temperature: -65°C ~ +150°C;

Operating Temperature: -55°C ~ +125°C;

Supply Current: 3mA;

Note: Operation of the device outside the parameter ranges given absolute-maximum-ratings conditions may cause permanent damage, and exposure to absolute-maximum-ratings conditions for extended periods will affect the reliability.

Note: when VDD=5V, Vctl=0V/3.3V can also work normally; But when VDD=3.3V, Vctl=0V/5V will not work properly.

ESD WARNING

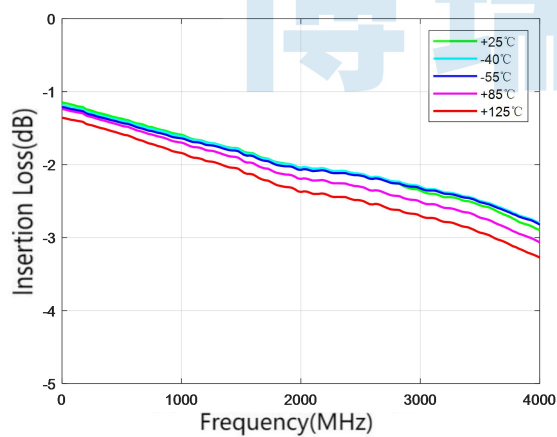


ELECTROSTATIC SENSITIVE DEVICE

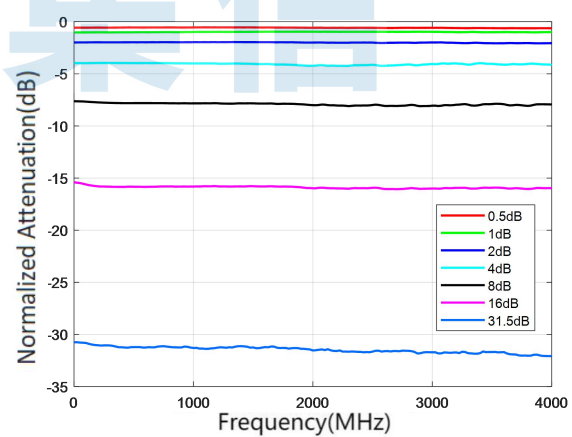
OBSERVE HANDLING PRECAUTIONS

Typical Performance (EVB test results)

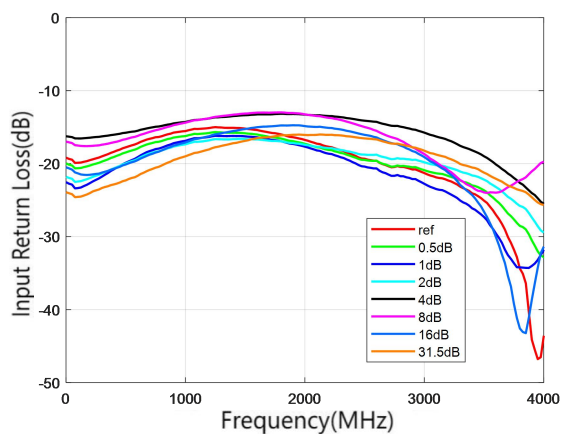
Parameter	Typ.							Units
Frequency	10	100	600	1000	2000	3000	4000	MHz
Reference State Insertion loss	-1	-1.2	-1.4	-1.6	-2	-2.3	-2.9	dB
Attenuation Accuracy (0.5dB)	-0.11	-0.07	-0.01	-0.03	-0.07	-0.08	-0.12	dB
Attenuation Accuracy (1 dB)	-0.03	-0.03	0.03	0.02	0.06	0.02	0.01	dB
Attenuation Accuracy (2 dB)	-0.04	-0.02	0.05	0.03	-0.01	-0.03	-0.09	dB
Attenuation Accuracy (4 dB)	0.01	-0.01	0.01	-0.04	-0.25	-0.20	-0.16	dB
Attenuation Accuracy (8 dB)	0.26	0.27	0.12	0.05	-0.23	-0.13	0.17	dB
Attenuation Accuracy (16 dB)	0.48	0.27	0.07	0.05	-0.25	-0.16	-0.02	dB
Attenuation Accuracy (31.5dB)	0.67	0.47	-0.08	0.31	-0.37	-0.41	-0.76	dB
Input Return Loss	-18.66	-20.1	-17.26	-15.77	-16.98	-20.1	-42	dB
Output Return Loss	-19.43	-20.1	-17.26	-15.77	-18.96	-24.8	-30.76	dB
Input Power for 1dB Compression	13.6	22.5	30.6	31.7	33	-	-	dBm
Switching Time	66.7ns rise switch				66.7ns down switch			ns
Test Conditions: VDD=+5V, I=3mA, Temp. =+25°C								



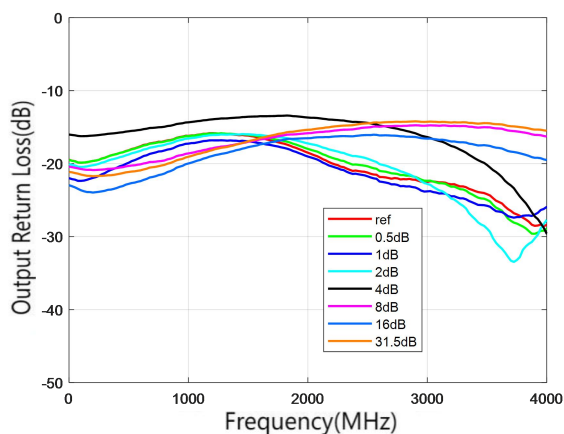
Insertion Loss



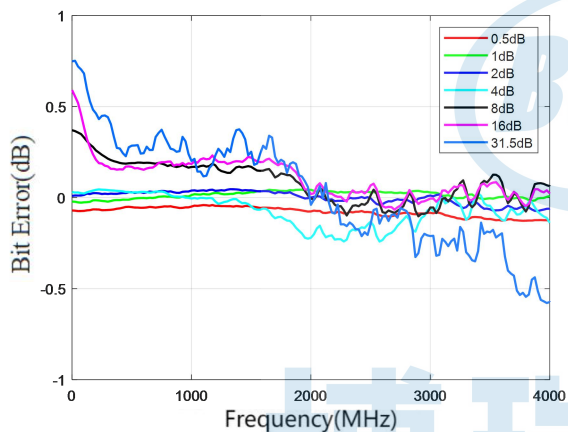
Normalized Attenuation



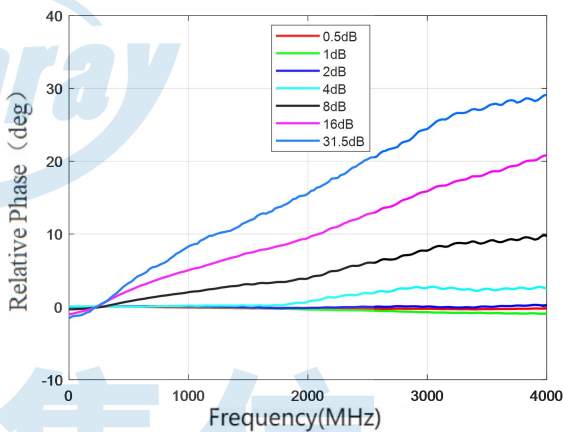
Input Return Loss



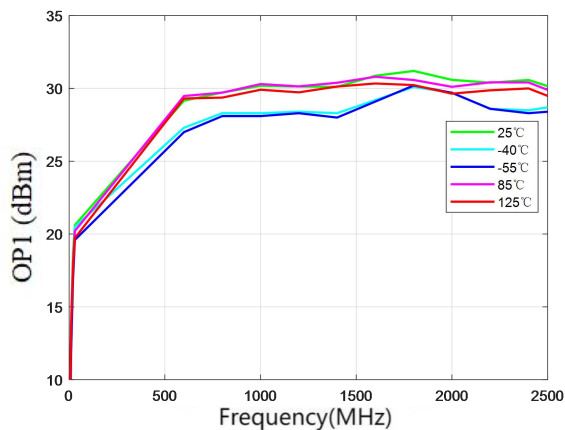
Output Return Loss



Bit Error

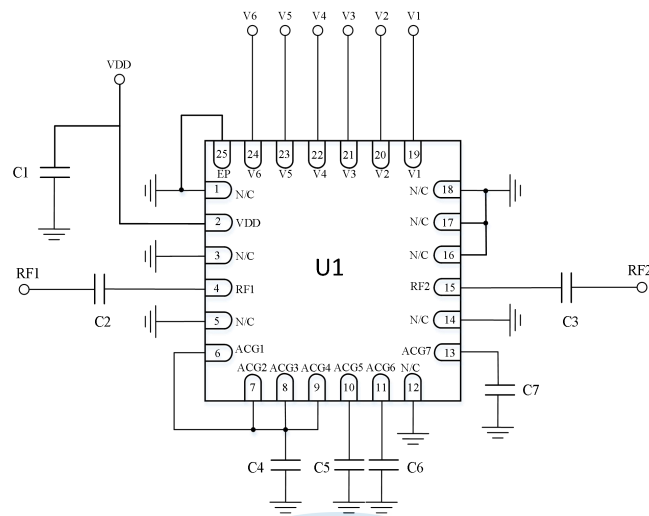


Relative Phase



Input Power for 1dB Compression

Typical Application Schematic



Bill of Material

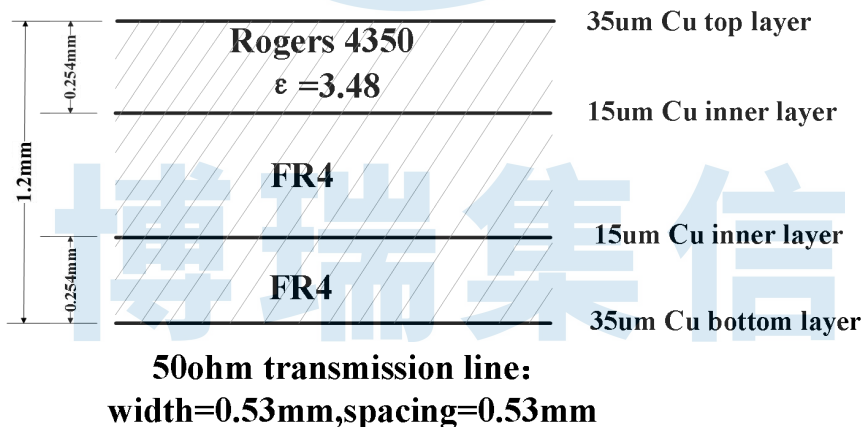
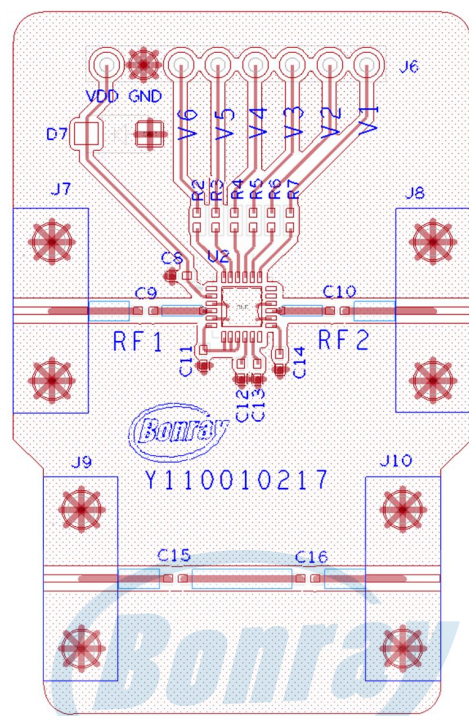
Reference Designator	Package	Description	Part Number
C1	0402	1nF	GRM1555C1H102JA01D
C2~C7	0402	1uF	GRM1555C1H105JA01

Control Voltage Truth Table

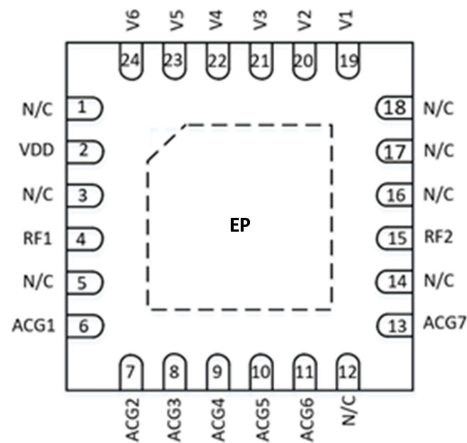
Control Voltage Inputs						Attenuation State
V1 16dB	V2 8dB	V3 4dB	V4 2dB	V5 1dB	V6 0.5 dB	RF1/RF2
1	1	1	1	1	1	Insertion loss in reference state
1	1	1	1	1	0	0.5 dB
1	1	1	1	0	1	1 dB
1	1	1	0	1	1	2 dB
1	1	0	1	1	1	4 dB
1	0	1	1	1	1	8 dB
0	1	1	1	1	1	16 dB
0	0	0	0	0	0	31.5dB

Note: Any combination of the above states will provide an attenuation approximately equal to the sum of the bits selected.

PCB Evaluation Board

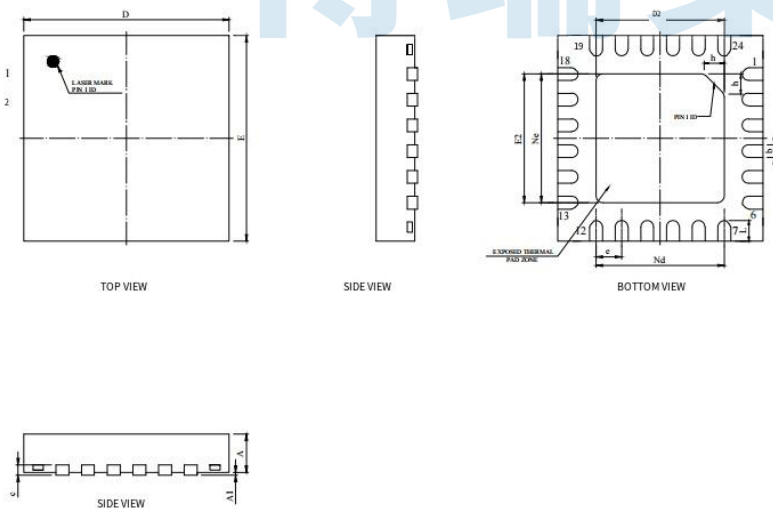


Pin Configuration and Description



Pin Number	Pin Name	Description
1,3,5,12, 14,16,17,18	N/C	No electrical connection. These pins should be connected to ground
2	VDD	Power supply pin.
4, 15	RF1, RF2	Attenuator RF input/output pins. DC block is required.
6 to 11,13	ACG1 ~ ACG7	External capacitors to ground are recommended for low and high frequency operation. Select value for lowest frequency of operation. Place capacitor as close to pins as possible.
19~24	V1-V6	Parallel control voltage input pins. Select the required attenuation. See Truth Table.
-	EP	Exposed pin. The exposed pad must be connected to RF/DC ground.

Package Dimensions (mm)



SYMBOL	MILLIMETER		
	MIN	NOM	MAX
A	0.75	0.80	0.85
A1	0.01	0.02	0.05
b	0.20	0.25	0.30
c	0.270REF		
D	3.90	4.00	4.10
D2	2.60	2.70	2.80
e	0.50BSC		
Ne	2.50BSC		
Nd	2.50BSC		
E	3.90	4.00	4.10
E2	2.60	2.70	2.80
L	0.35	0.40	0.45
h	0.35	0.40	0.45